

OSCELOT FAST TURNAROUND VCXO

DESCRIPTION

The **OSCELOT** VCXO series is a cutting edge family of low to high frequency, **low jitter output**, **single** or **multi - frequency** voltage controlled clock oscillators. The **OSCELOT** VCXO's are available in **7.0 x 5.0, 5.0 x 3.2, or 3.2 x 2.5 mm** ceramic packages with output frequencies ranging from **10 MHz to 1.2 GHz**. Its outstanding flexibility significantly reduces design cycle time and overall cost. The **OSCELOT** design incorporates a low frequency crystal along with low jitter frequency synthesizer to provide a wide range of frequencies. The **OSCELOT** VCXO's are available in **LVC MOS, LVPECL** and **LVDS** outputs, allowing for a wide variety of applications. This product is ideal for the time conscious customer as shipments are made within days of a placed order.

FEATURES

- **Fast Turnaround (Ships Within Days)**
- **Very Low Jitter (Typical 0.6 ps)**
- **10 MHz to 1.2 GHz Frequency Range**
- **Selectable Single or Dual Frequency**
- **Available Sizes:**
 - ✓ **7.0 x 5.0 mm**
 - ✓ **5.0 x 3.2 mm**
 - ✓ **3.2 x 2.5 mm**

SELECTOR GUIDE	LVC MOS			LVDS			LVPECL		
	3.2x2.5	5.0x3.2	7.0x5.0	3.2x2.5	5.0x3.2	7.0x5.0	3.2x2.5	5.0x3.2	7.0x5.0
Package Size (mm)	3.2x2.5	5.0x3.2	7.0x5.0	3.2x2.5	5.0x3.2	7.0x5.0	3.2x2.5	5.0x3.2	7.0x5.0
Family Part Number	HC3	HC5	HC7	LC3	LC5	LC7	PC3	PC5	PC7
Frequency Range (MHz)	10 – 250			10 – 1200			10 - 1200		
Absolute Pull Range (ppm)	±20, ±25, ±50, ±100			±20, ±25, ±50, ±100			±20, ±25, ±50, ±100		
Number of Frequencies	1, 2			1, 2			1, 2		
Supply Voltage (V)	2.5, 3.3			2.5, 3.3			2.5, 3.3		
Temperature Range (°C)	-20 ~ +70			-20 ~ +70			-20 ~ +70		
	-40 ~ +85			-40 ~ +85			-40 ~ +85		

OUTPUT CHARACTERISTICS

	PARAMETER	SYMBOL	CONDITION	VALUE			UNIT	
				Min	Typ.	Max		
LVC MOS	Frequency Range	f_o		10		250	MHz	
	Output Levels	V_{OH}		$0.9V_{cc}$			V	
		V_{OL}				$0.1V_{cc}$	V	
	Rise/Fall Time	T_r/T_f	20% - 80% (V_{OL} , V_{OH})			0.5	ns	
	Supply Current	I_s	2.5V	10 – 50 MHz			30	mA
				51 – 135 MHz			45	
				136 – 250 MHz			55	
			3.3V	10 – 50 MHz			35	
51 – 135 MHz						50		
136 – 250 MHz						60		
Output Load	O_{CL}	Standard			15	pF		

	PARAMETER	SYMBOL	CONDITION	VALUE			UNIT	
				Min	Typ.	Max		
LVPECL	Frequency Range	f_o		10		1200	MHz	
	Output levels	V_{OH}	Load 50Ω to $V_{cc}-2V$	$V_{cc}-1.03$		$V_{cc}-0.6$	V	
		V_{OL}		$V_{cc}-1.85$		$V_{cc}-1.6$	V	
	Rise/Fall Time	T_r/T_f				0.25	ns	
	Output Voltage Swing	V_{p-p}	Output termination 50Ω / $V_{cc} - 2.0V$	0.6 ~ 1.0			V	
	Supply Current	I_s	2.5 V	10 – 50 MHz			35	mA
				51 – 215 MHz			45	
				216 – 640 MHz			65	
641 – 1200 MHz						70		
3.3V			10 – 50 MHz			85		
			51 – 215 MHz			95		
641 – 1200 MHz				115				
				120				
Output Load	O_{CL}	Output Termination 50Ω to $V_{cc}-2V$			50	Ω		



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HIGH FREQUENCY, LOW JITTER
VOLTAGE CONTROLLED CRYSTAL OSCILLATOR

	PARAMETER	SYMBOL	CONDITION	VALUE			UNIT	
				Min	Typ.	Max		
LVDS	Frequency Range	f_o		10		1200	MHz	
	Differential Output Voltage	V_{OD}	10 – 1200 MHz		0.6		V	
	Offset Voltage	V_{OS}	V DC		1.3		V	
	Rise/Fall Time	T_r/T_f				0.35	ns	
	Supply Current	I_s	2.5V	10 – 50 MHz			25	mA
				51 – 215 MHz			30	
				216 – 640 MHz			43	
				641 – 1200 MHz			60	
			3.3V	10 – 50 MHz			65	
				51 – 215 MHz			72	
216 – 640 MHz						83		
641 – 1200 MHz						100		
Output Load	O_{CL}	Differential 100Ω Load Connected Between Each Output			100	Ω		

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	CONDITION	VALUE			UNIT
			Min.	Typ.	Max.	
Supply Voltage ¹	V _{CC}			2.5 or 3.3		V
Duty Cycle	DC	Load depends on output type	45		55	%
RMS Phase Jitter	J	12 kHz – 20 MHz Bandwidth		0.6	1	ps
Absolute Pull Range ^{1,2}	$\Delta f/f_c$	Min. guaranteed frequency pull over $\Delta f/f_c$ -40°C to +85°C			± 20 ± 50 ± 100	ppm
Control Voltage	V _C	Centered = ½ (V _{CC})		1.25, 1.65		V
Control Voltage Range		Positive slope; 10% linearity			V _{CC}	V
Input Impedance	Z			500		kΩ
Modulation Bandwidth	BW	-3db	20			kHz
Start-Up Time	t _{start}	T _a =25°C			10	ms
Enable	En	Min (logic 1 or open) HCMOS levels	0.7V _{CC}			V
Disable ³	Dis	Max (logic 0) HCMOS levels			0.3	V
OE Function OE Pin Input LVCMOS/ LVTTTL	Input Capacitance	C _{IN}		4		pF
	Input High Voltage	V _{IH}	0.7V _{CC}			V
	Input Low Voltage	V _{IL}			0.3V _{CC}	V
	Input High Current	I _{IH}			5	μA
	Input Low Current	I _{IL}		-10		μA
	Equivalent Internal Pull-up Resistance	R _{PULLUP}			900	
Aging		First year			±5	ppm
		Year thereafter			±2	
Operating Temperature ¹	T _a		-40		+85	°C
Storage Temperature	T _(stg)	Absolute max	-45		+100	°C
Absolute Voltage Range	V _{CC(abs)}				4.6	V
Moisture Sensitivity Level	MSL	JEDEC J-STD-020			1	
Termination Finish			Au			
ESD Sensitivity	HBM	Human body model JESD22-A114			3	kV

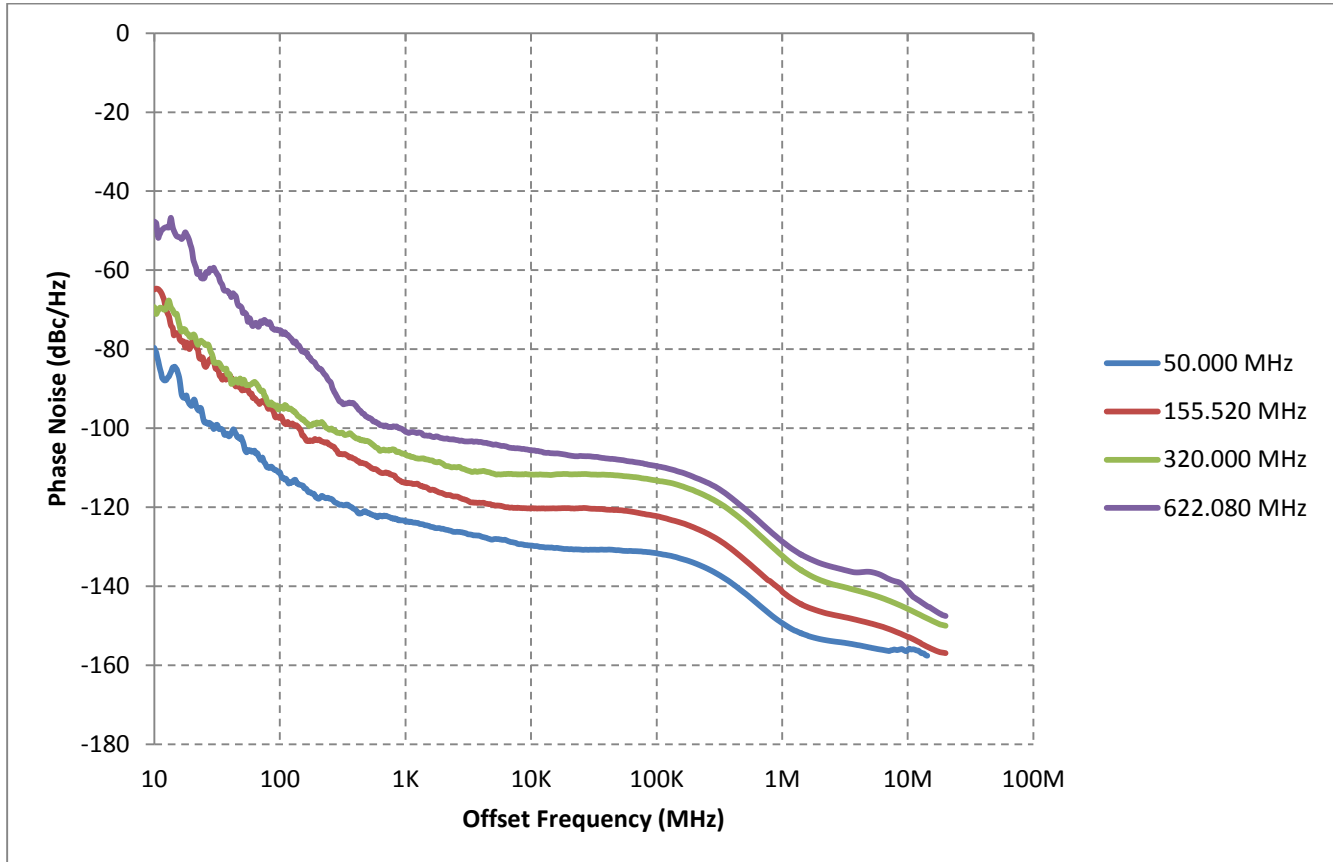
Notes

¹ See part numbering table

² Inclusive of 25°C calibration, tolerance, operating temperature range, input voltage variation, load change, aging, shock and vibration

³ Output goes to high impedance

PHASE NOISE AND JITTER PERFORMANCE

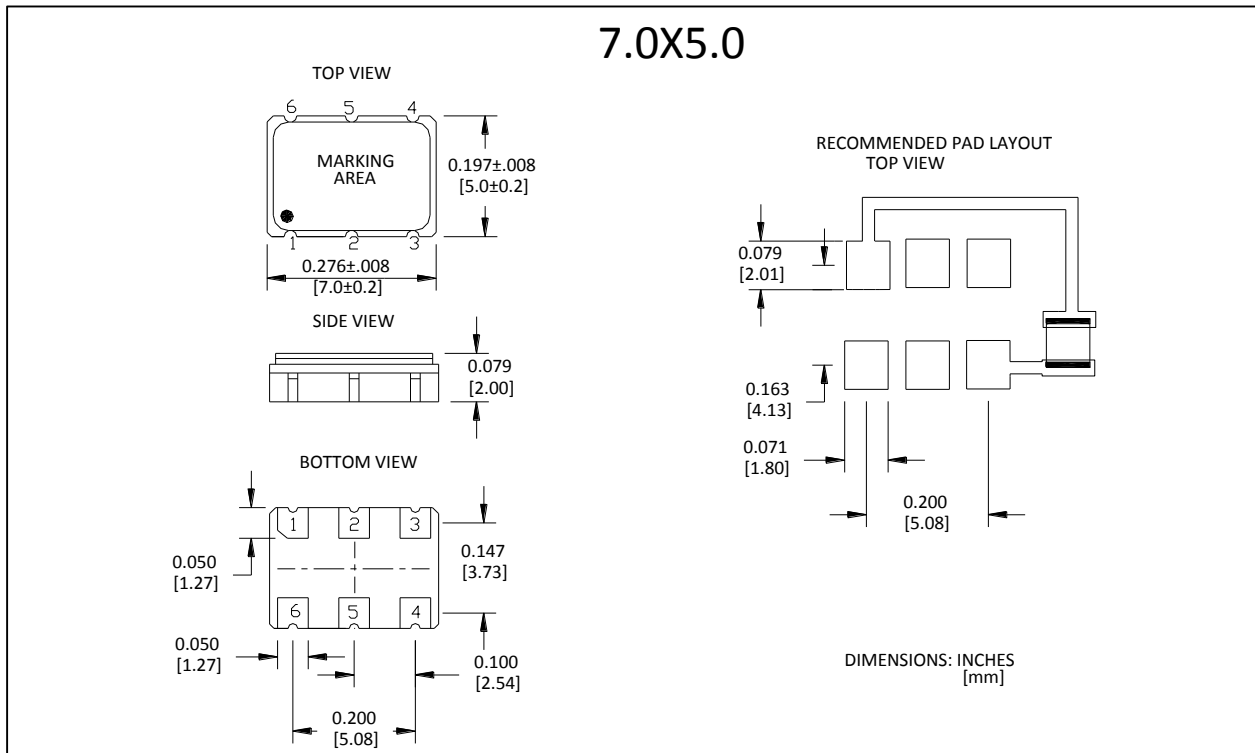


Data collected using Agilent E5052B signal source analyzer. $V_{cc} = 2.5V$.

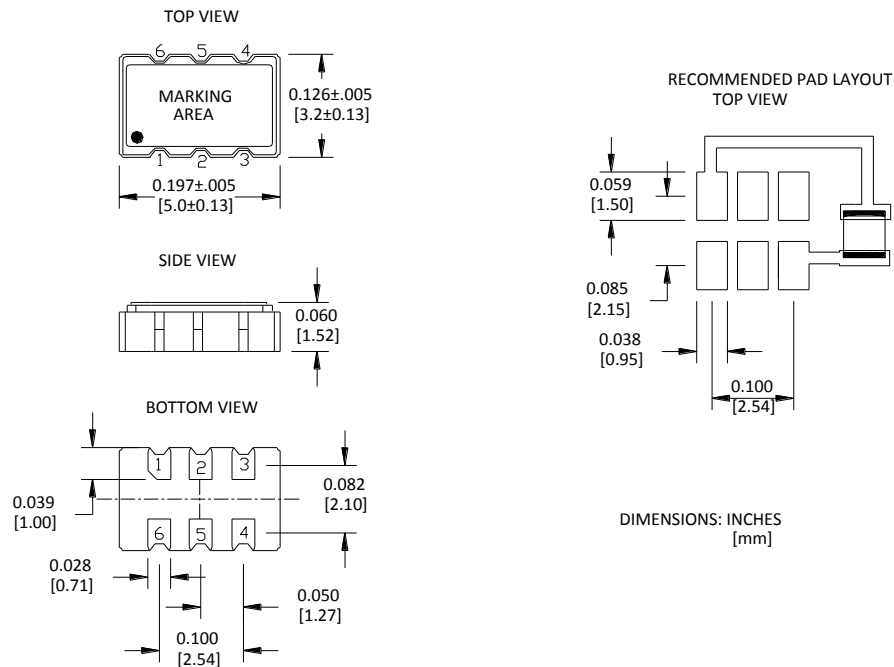
FREQUENCY (MHz)	FULL BANDWIDTH PHASE JITTER (ps)	PHASE JITTER 12 kHz to 20 MHz INTEGRATED BANDWIDTH (ps RMS)
50.000	3.0	0.9
155.520	2.1	0.6
320.000	3.2	0.7
622.080	3.3	0.7

Phase jitter integrated using Agilent E5052B signal source analyzer. $V_{cc} = 2.5V$ (LVCMOS, LVDS, LCPECL – load)

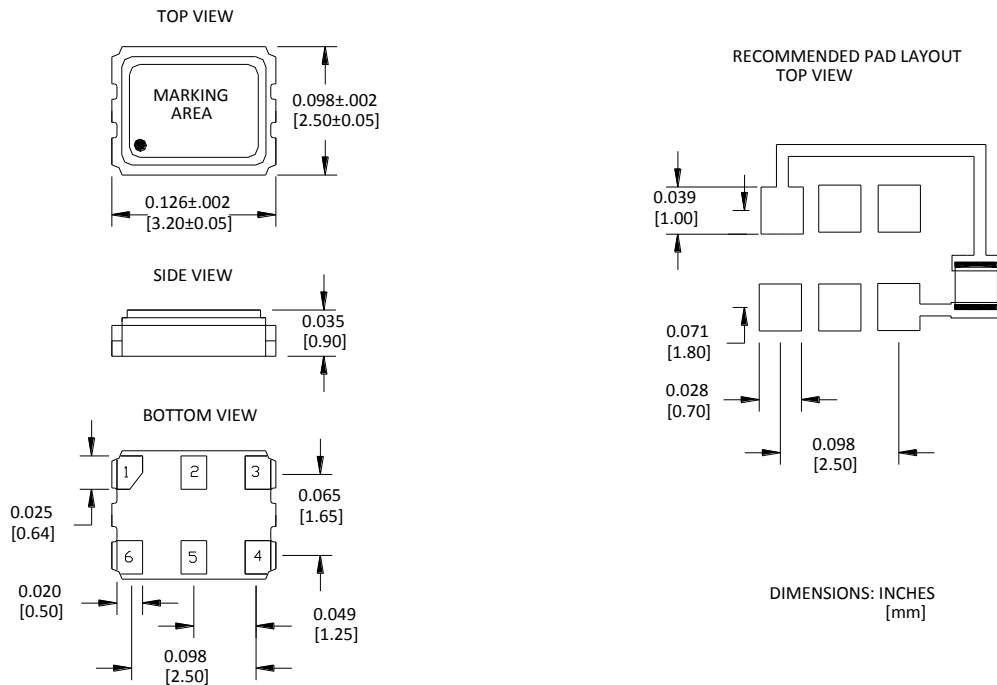
MECHANICAL DIMENSIONS AND PIN FUNCTIONING



5.0X3.2



3.2X2.5



Notes (Applicable To All Packages)

¹ Enable / Disable feature is available on either pin 1 or pin 2. See options on part numbering table.

³ 0.01 µF external bypass capacitor is recommended as seen in solder pattern for 7 x 5 mm, and required for 5 x 3.2 and 3.2 x 2.5 mm



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**HIGH FREQUENCY, LOW JITTER
VOLTAGE CONTROLLED CRYSTAL OSCILLATOR**

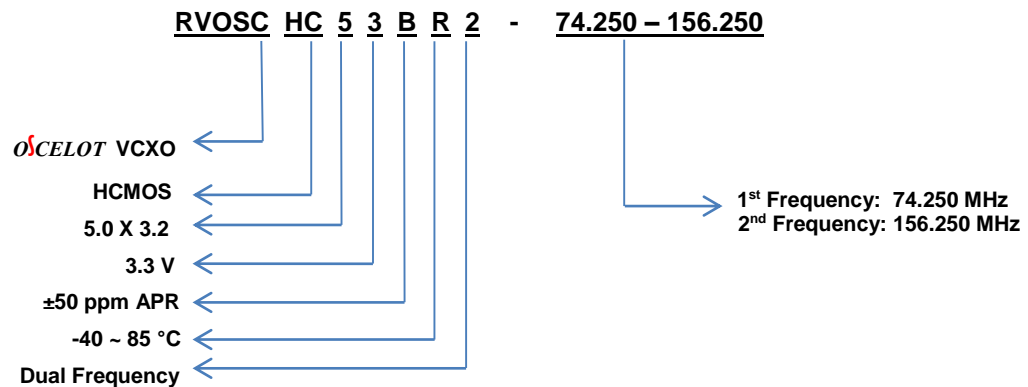
PIN	SYMBOL	FUNCTION
1	V _C	Control Voltage
2	see below	Refer to Pin Logic Table Below
3	GND	Case and Electrical Ground
4	Output 1	Output 1
5	Output 2 or NC	Complementary Output (LVPECL, LVDS) or N/C (LVCMOS)
6	V _{CC}	Power Supply Voltage

PIN LOGIC TABLE			
NUMBER OF FREQUENCIES	PIN 1	PIN 2	FREQUENCY OUTPUT
1	Control Voltage	N/C	F ₁
		Enable/Disable	F ₁
2	Control Voltage	"0" Logic Level	F ₁
		"1" Logic Level	F ₂

PART NUMBERING

SERIES	OUTPUT	SIZE (mm)	SUPPLY VOLTAGE (V)	APR (ppm)	TEMP RANGE (°C)	NUMBER OF FREQUENCIES	-	OUTPUT FREQUENCY (MHz)
RVOSC	HC =CMOS LV =LVDS PC= LVPECL	3=3.2x2.5 5=5.0x3.2 7=7.0x5.0	2: V _{cc} = 2.5 3: V _{cc} = 3.3	K: ±20 B: ±50 J: ±100	blank: -20~70 R: -40~85	blank: Single 2: Dual	-	F ₁ F ₁ - F ₂

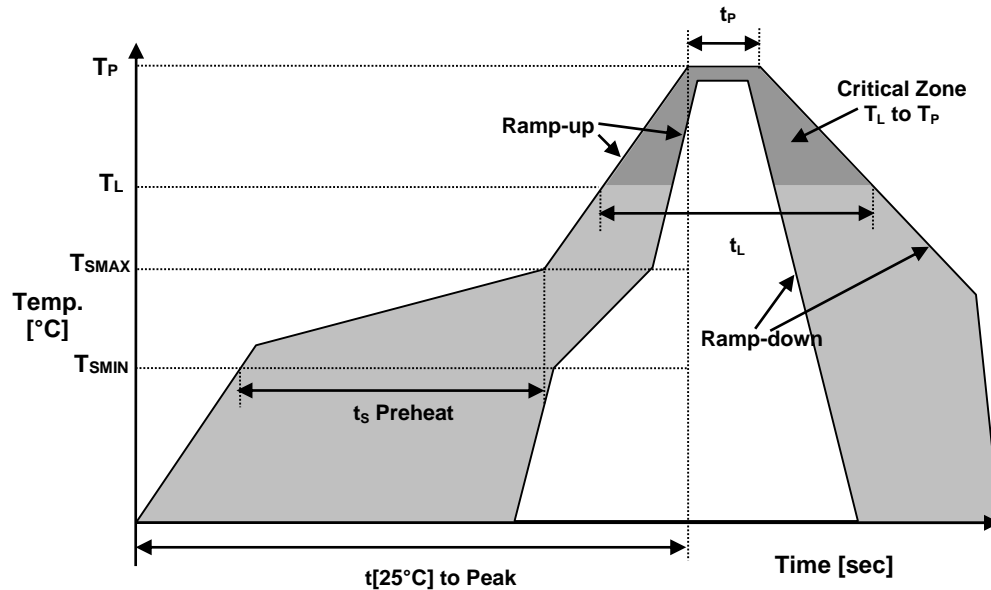
EXAMPLE:



MARKING

- A marking code will be issued by the sales department at order confirmation.

REFLOW PROFILE



Recommended Solder Reflow Profile			
Temperature Min Preheat	T_{SMIN}		150°C
Temperature Max Preheat	T_{SMAX}		175°C
Time (T_{SMIN} to T_{SMAX})	t_s		60-180 sec.
Temperature	T_L		217°C
Peak Temperature	T_P		260°C
Ramp-up rate	R_{UP}		3°C/sec max.
Ramp-down rate	R_{DOWN}		6°C/sec max.
Time within 5°C of Peak Temperature	t_p		10 sec max.
Time $t[25^\circ\text{C}]$ to Peak Temperature	$t[25^\circ\text{C}]$ to Peak		480 sec.
Time	t_L		60-150 sec.

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